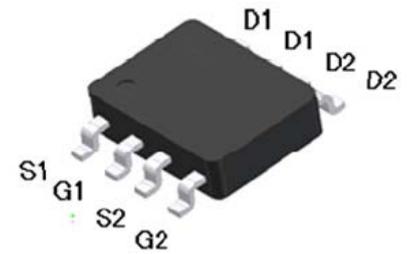
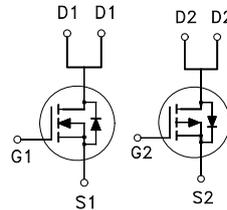


N & P-Channel Logic Level Enhancement Mode Field Effect Transistor

Product Summary:

	N-CH	P-CH
BV _{DSS}	20V	-20V
R _{DS(on)} (MAX.)	20mΩ	40mΩ
I _D	6A	-5A



UIS, Rg 100% Tested

Pb-Free Lead Plating & Halogen Free



ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C Unless Otherwise Noted)

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS		UNIT
Gate-Source Voltage		V _{GS}	N-CH	P-CH	V
			±12	±12	
Continuous Drain Current	T _A = 25 °C	I _D	6	-5	A
	T _A = 100 °C		4	-3.3	
Pulsed Drain Current ¹		I _{DM}	24	-20	
Avalanche Current		I _{AS}	6	-5	
Avalanche Energy	L = 0.1mH, I _D =6A, R _G =25Ω (N) L = 0.1mH, I _D =-5A, R _G =25Ω (P)	E _{AS}	1.8	1.25	mJ
Repetitive Avalanche Energy ²	L = 0.05mH	E _{AR}	0.9	0.625	
Power Dissipation	T _A = 25 °C	P _D	2		W
	T _A = 100 °C		0.8		
Operating Junction & Storage Temperature Range		T _j , T _{stg}	-55 to 150		°C

THERMAL RESISTANCE RATINGS

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNIT
Junction-to-Case	R _{θJC}		25	°C/W
Junction-to-Ambient ³	R _{θJA}		62.5	

¹Pulse width limited by maximum junction temperature.

²Duty cycle ≤ 1%

³62.5°C/W when mounted on a 1 in² pad of 2 oz copper.

ELECTRICAL CHARACTERISTICS ($T_c = 25\text{ }^\circ\text{C}$, Unless Otherwise Noted)

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
STATIC						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$ $V_{GS} = 0V, I_D = -250\mu A$	N-CH	20		V
			P-CH	-20		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$ $V_{DS} = V_{GS}, I_D = -250\mu A$	N-CH	0.45	0.75	1.2
			P-CH	-0.45	-0.75	-1.2
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0V, V_{GS} = \pm 12V$ $V_{DS} = 0V, V_{GS} = \pm 12V$	N-CH			± 100
			P-CH			± 100
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 16V, V_{GS} = 0V$ $V_{DS} = -16V, V_{GS} = 0V$	N-CH			1
			P-CH			-1
			N-CH			10
			P-CH			-10
On-State Drain Current ¹	$I_{D(ON)}$	$V_{DS} = 5V, V_{GS} = 4.5V$ $V_{DS} = -5V, V_{GS} = -4.5V$	N-CH	6		A
			P-CH	-5		
Drain-Source On-State Resistance ¹	$R_{DS(ON)}$	$V_{GS} = 4.5V, I_D = 6A$ $V_{GS} = -4.5V, I_D = -5A$ $V_{GS} = 2.5V, I_D = 5A$ $V_{GS} = -2.5V, I_D = -4A$	N-CH		18	20
			P-CH		37	44
			N-CH		23	28
			P-CH		55	70
Forward Transconductance ¹	g_{fs}	$V_{DS} = 5V, I_D = 6A$ $V_{DS} = -5V, I_D = -5A$	N-CH		8	S
			P-CH		14	
DYNAMIC						
Input Capacitance	C_{iss}	N-CH $V_{GS} = 0V, V_{DS} = 15V, f = 1MHz$	N-CH		560	pF
			P-CH		679	
Output Capacitance	C_{oss}	P-CH $V_{GS} = 0V, V_{DS} = -15V, f = 1MHz$	N-CH		166	pF
			P-CH		124	
Reverse Transfer Capacitance	C_{rss}		N-CH		150	pF
			P-CH		106	

Gate Resistance	R_g	$V_{GS} = 15mV, V_{DS} = 0V, f = 1MHz$	N-CH		2.0	3.0	Ω
			P-CH		4.4	6.6	
Total Gate Charge ^{1,2}	Q_g	N-CH $V_{DS} = 10V, V_{GS} = 4.5V,$ $I_D = 6A$ P-CH $V_{DS} = -10V, V_{GS} = -4.5V,$ $I_D = -5A$	N-CH		8.5		nC
Gate-Source Charge ^{1,2}	Q_{gs}		P-CH		12.8		
			N-CH		1.5		
Gate-Drain Charge ^{1,2}	Q_{gd}		P-CH		2.2		
			N-CH		3.5		
			P-CH		4.1		
Turn-On Delay Time ^{1,2}	$t_{d(on)}$	N-CH $V_{DS} = 10V,$ $I_D = 1A, V_{GS} = 4.5V, R_{GS} = 6\Omega$ P-CH $V_{DS} = -10V,$ $I_D = -1A, V_{GS} = -4.5V, R_{GS} = 6\Omega$	N-CH		12		nS
Rise Time ^{1,2}	t_r		P-CH		10		
			N-CH		15		
Turn-Off Delay Time ^{1,2}	$t_{d(off)}$		P-CH		18		
			N-CH		30		
Fall Time ^{1,2}	t_f		P-CH		32		
			N-CH		13		
			P-CH		22		
SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS ($T_c = 25^\circ C$)							
Continuous Current	I_s		N-CH			2.3	A
			P-CH			-2.3	
Pulsed Current ³	I_{SM}		N-CH			9.2	
			P-CH			-9.2	
Forward Voltage ¹	V_{SD}	$I_F = I_s, V_{GS} = 0V$	N-CH			1.3	V
			P-CH			-1.3	

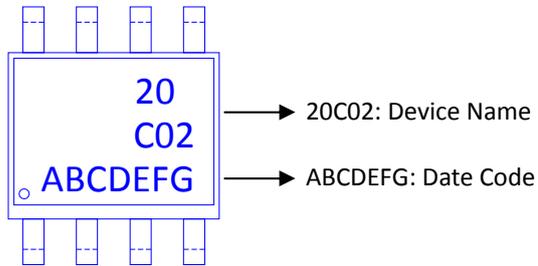
¹Pulse test : Pulse Width $\leq 300 \mu sec$, Duty Cycle $\leq 2\%$.

²Independent of operating temperature.

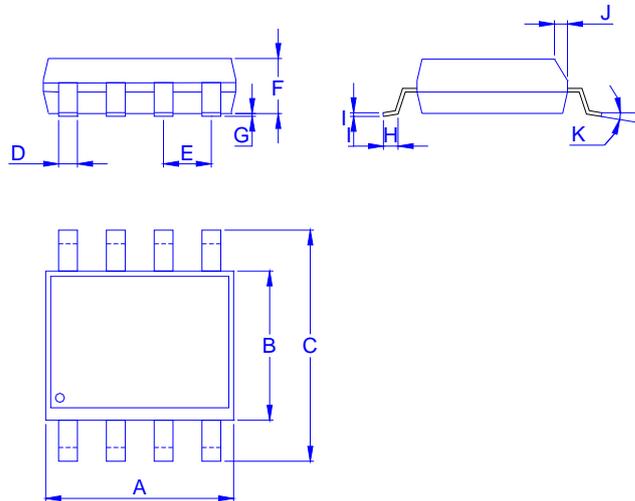
³Pulse width limited by maximum junction temperature.

Ordering & Marking
Information:

Device Name: LB20C02H for SOP-8



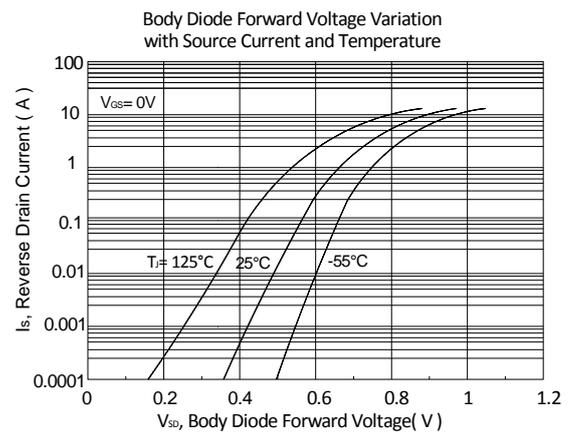
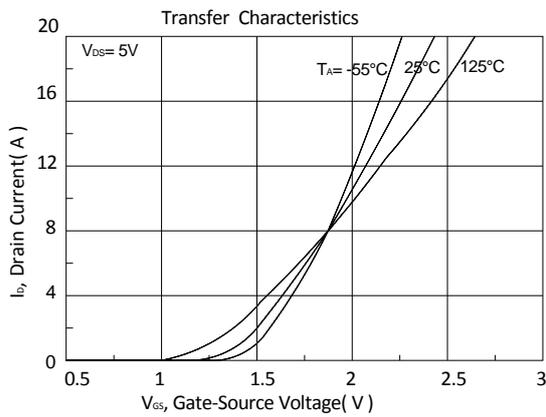
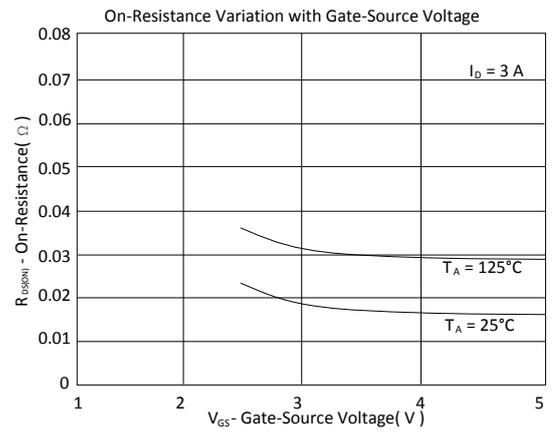
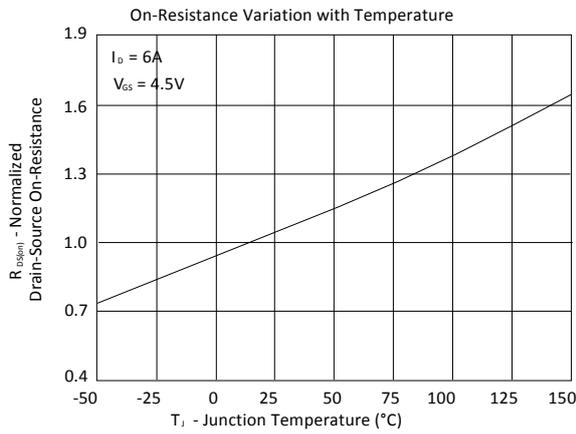
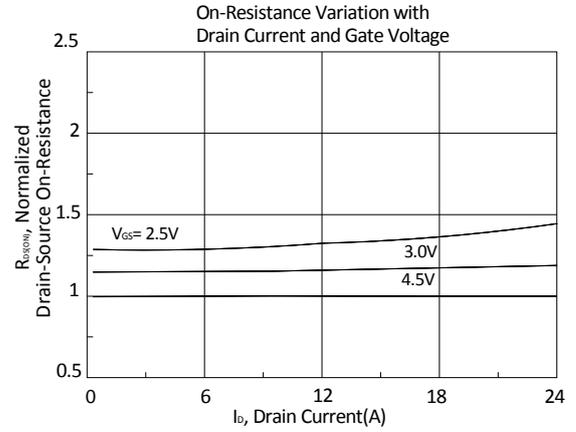
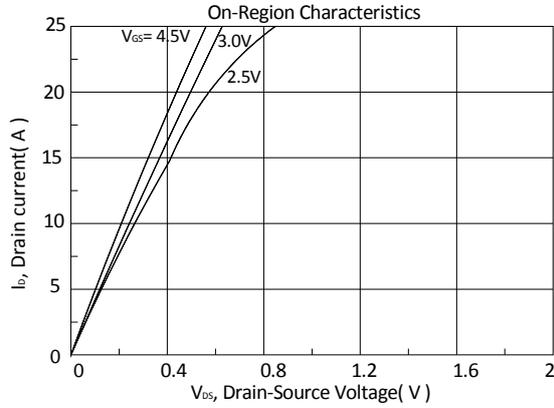
Outline Drawing

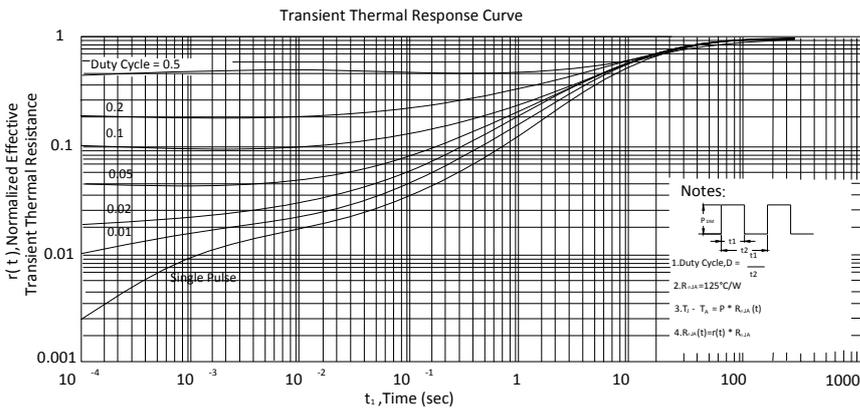
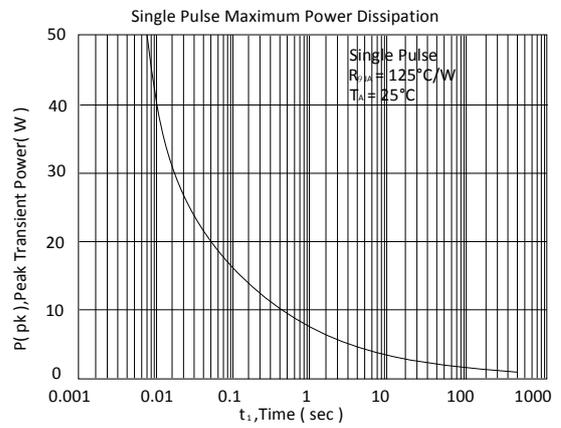
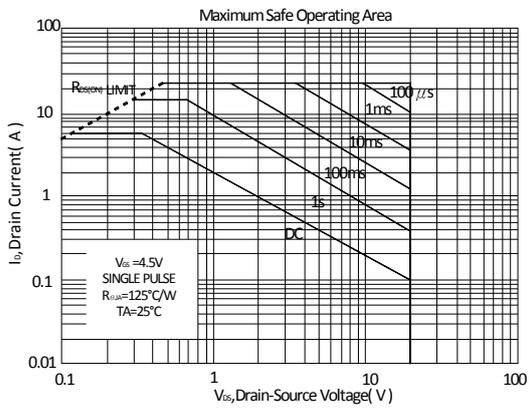
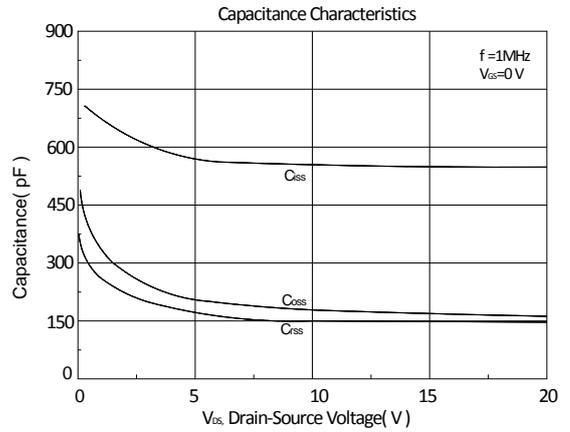
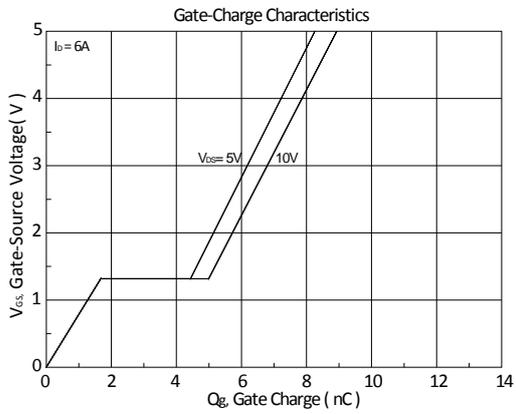


Dimension in mm

Dimension	A	B	C	D	E	F	G	H	I	J	K
Min.	4.70	3.70	5.80	0.33		1.20	0.08	0.40	0.19	0.25	0°
Typ.					1.27						
Max.	5.10	4.10	6.20	0.51		1.62	0.28	0.83	0.26	0.50	8°

N-Channel





P-Channel

